GLF71311H

Nano-Current Consumed I_QSmart™ Power Load Switch with Slew Rate Control

Product Specification

DESCRIPTION

The GLF71311H is an ultra-efficiency, 3 A rated, load switch with integrated slew rate control. The best in class efficiency makes it an ideal chose for use in IoT, mobile, and wearable electronics.

The GLF71311H features ultra-efficient I_QSmart™ technology that supports the lowest quiescent current (I_Q) and shutdown current (I_{SD}) in the industry. Low I_Q and I_{SD} solutions help designers to reduce parasitic leakage current, improve system efficiency and increase battery lifetime.

The GLF71311H integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF71311H slew rate control specifically limits inrush currents during turn-on to minimize voltage droop.

GLF71311H Load Switch devices support an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduce operating cost.

GLF71311H Load Switch device is small utilizing a chip scale package with 4 bumps in a 0.97 mm x 0.97 mm x 0.55 mm die size and a 0.5 mm bump pitch.

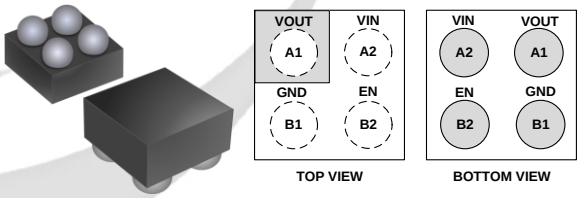
FEATURES

- Ultra-Low I_Q: 7 nA Typ at 5.5 V_{IN}
- Ultra-Low I_{SD}: 28 nA Typ at 5.5 V_{IN}
- Low R_{ON} : 31 mΩ Typ at 5.5 V_{IN}
- I_{OUT} Max: 3 A
- Wide Input Range: 1.1 V to 5.5 V
  6 V_{ABS} max
- Controlled Rise Time: 335 µs at 3.3 V_{IN}
- Internal EN Pull-Down Resistor
- Integrated Output Discharge Switch
- Wide Operation Temperature Range:
  - 40 ℃ to 105 ℃
- Ultra-Small: 0.97 mm x 0.97 mm

APPLICATIONS

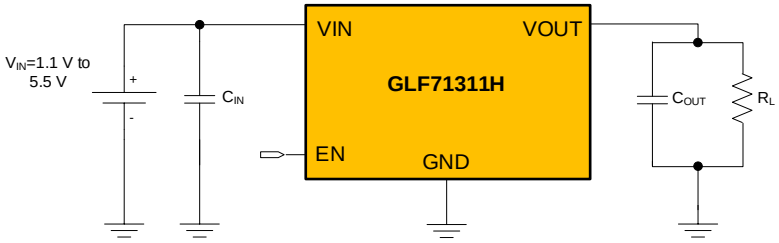
- Wearables
- Data Storage, SSD
- Mobile Devices
- Low Power Subsystems

PACKAGE



0.97 mm x 0.97 mm x 0.55 mm WLCSP

APPLICATION DIAGRAM



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DEVICE INFORMATION

Part Number	Top Mark	RON (Typ.) at 5.5 V	Output Discharge	EN Activity	Availability
GLF71311H	DZ	31 mΩ	85 Ω	High	Released

FUNCTIONAL BLOCK DIAGRAM

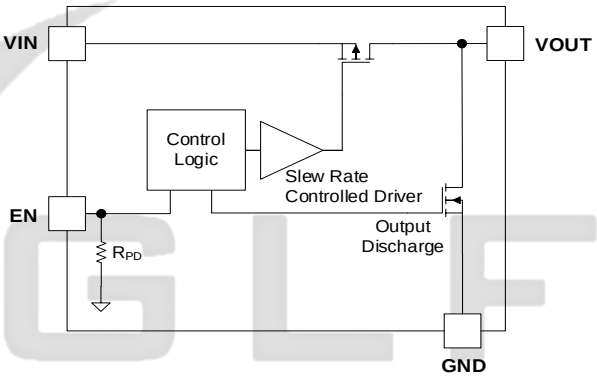

Figure 1. Functional Block Diagram

PIN CONFIGURATION

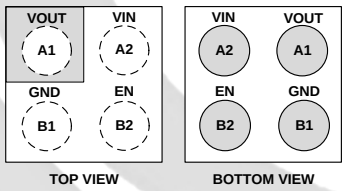

Figure 2. 0.97 mm x 0.97 mm x 0.55 mm WLCSP

PIN DEFINITION

Pin #	Name	Description
A1	VOUT	Switch Output
A2	VIN	Switch Input. Supply Voltage for IC
B1	GND	Ground
B2	EN	Enable to control the switch

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ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V_{IN}, V_{OUT}, V_{EN}	Each Pin Voltage Range to GND		- 0.3	6	V
I_{OUT} (1)	Maximum Continuous Switch Current at T_A = 25°C, ≥ 1.5 V			3	A
P_D	Power Dissipation at T_A = 25°C			1.2	W
T_{STG}	Storage Temperature		- 65	150	°C
T_J	Maximum Junction Temperature			150	°C
T_A	Operating Temperature Range		- 40	105	°C
θ_{JA}	Thermal Resistance, Junction to Ambient			85	°C/W
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	± 6		kV
		Charged Device Model, JESD22-C101	± 2		

Notes: 1. It is limited by thermal design such as maximum junction temperature, device power dissipation, on-resistance at operating conditions and a PCB board. The maximum output current rating is degraded as power dissipation of the device increases. The maximum output current and the junction temperature are theoretically calculated using the equation, $T_J = T_A + P_D (R_{ON} \times I_{OUT}^2) \times R_{\theta JA}$.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V_{IN}	Supply Voltage	1.1	5.5	V
T_A	Ambient Operating Temperature	- 40	+ 105	°C

ELECTRICAL CHARACTERISTICS

Values are at V_{IN} = 3.3 V and T_A = 25 °C unless otherwise noted.

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Unit
Basic Operation							
V_{IN}	Supply Voltage			1.1		5.5	V
I_Q	Quiescent Current (1)	V_{IN} = V_{EN} = 5.5 V, I_{OUT} = 0 mA			7	70	nA
		V_{IN} = V_{EN} = 5.5 V, I_{OUT} = 0 mA, T_A = 85 °C (4)			12		
		V_{IN} = V_{EN} = 5.5 V, I_{OUT} = 0 mA, T_A = 105 °C (4)			27		
I_{SD}	Shut Down Current	EN = Disable, I_{OUT} = 0 mA, V_{IN} = 1.1 V			5		
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 1.8 V			6		
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 3.3 V			9	35	
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 4.5 V			13		
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 5.5 V			28	100	
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 5.5 V, T_A = 55 °C (4)			150		
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 5.5 V, T_A = 85 °C (4)			1000		
		EN = Disable, I_{OUT} = 0 mA, V_{IN} = 5.5 V, T_A = 105 °C (4)			2300		
R_{ON}	On-Resistance	V_{IN} = 5.5 V, I_{OUT} = 500 mA	T_A = 25 °C		31	34	mΩ
			T_A = 85 °C (4)		36		
			T_A = 105 °C (4)		38		

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ELECTRICAL CHARACTERISTICS (CONTINUED)

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Unit
R_{ON}	On-Resistance	V_{IN} = 3.3 V, I_{OUT} = 500 mA	T_A = 25 °C		36	41	
			T_A = 85 °C (4)		43		
			T_A = 105 °C (4)		45		
		V_{IN} = 1.8 V, I_{OUT} = 300 mA	T_A = 25 °C		52	60	
		V_{IN} = 1.1 V, I_{OUT} = 100 mA	T_A = 25 °C		95	120	
R_{DSC}	Output Discharge Resistance	EN = High , I_{FORCE} = 10 mA		70	85	100	Ω
V_{IH}	EN Input Logic High Voltage	V_{IN} = 1.1 V - 1.8 V		0.9			V
		V_{IN} = 1.8 V - 5.5 V		1.2			V
V_{IL}	EN Input Logic Low Voltage	V_{IN} = 1.1 V - 1.8 V				0.3	V
		V_{IN} = 1.8 V - 5.5 V				0.4	V
R_{EN}	EN internal resistance	Internal Pull-down Resistance			9.5		MΩ
I_{EN}	EN Current	EN = 5.5 V				1.0	μA
Switching Characteristics (2,4)							
t_{dON}	Turn-On Delay	R_L = 150 Ω, C_{OUT} = 0.1 μF			210		μs
t_R	V_{OUT} Rise Time				335		
t_{dOFF}	Turn-Off Delay	R_L = 150 Ω, C_{OUT} = 0.1 μF			0.7		
t_F	V_{OUT} Fall Time				10.5		

Notes:
1. I_Q does NOT include Enable pull down current through the pull-down resistor R_{DSC}.
2. $t_{ON} = t_{dON} + t_R$, $t_{OFF} = t_{dOFF} + t_F$
3. Output discharge path is enabled during off.
4. By design; characterized, not production tested.

TIMING DIAGRAM

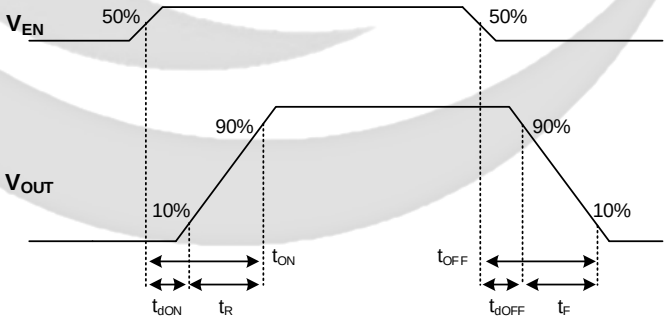

Figure 3. Timing Diagram

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TYPICAL PERFORMANCE CHARACTERISTICS

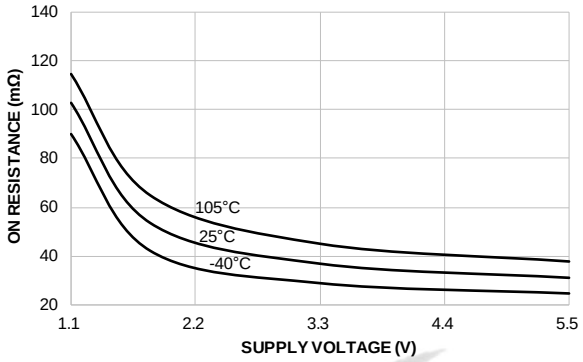

Figure 4. On-Resistance vs. Input Voltage

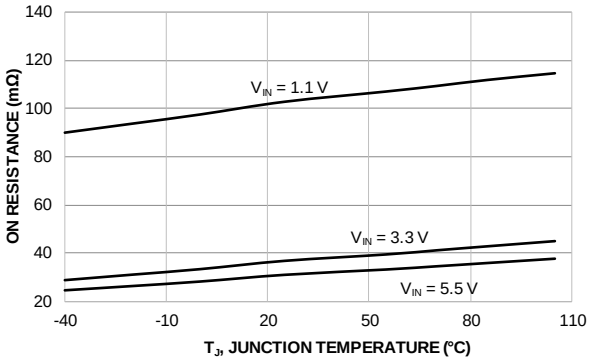

Figure 5. On-Resistance vs. Temperature

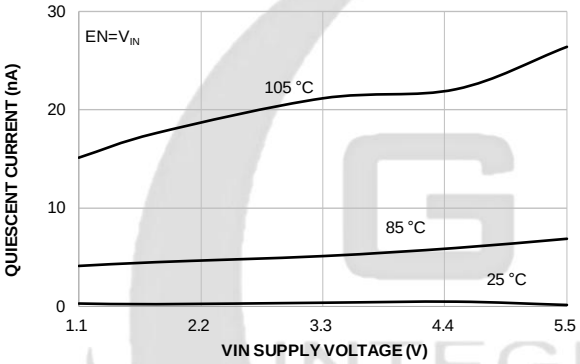

Figure 6. Quiescent Current vs. Input Voltage

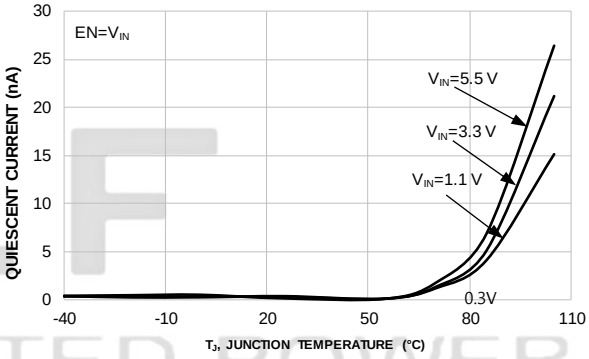

Figure 7. Quiescent Current vs. Temperature

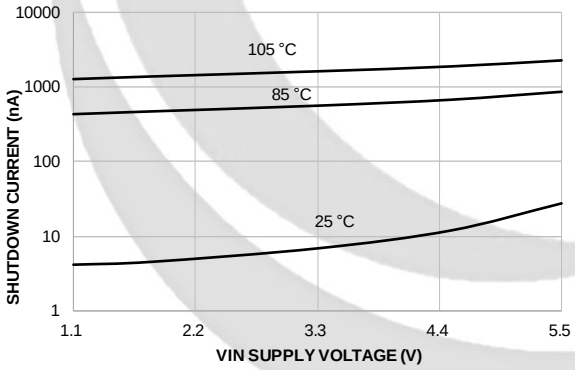

Figure 8. Shut Down Current vs. Input Voltage

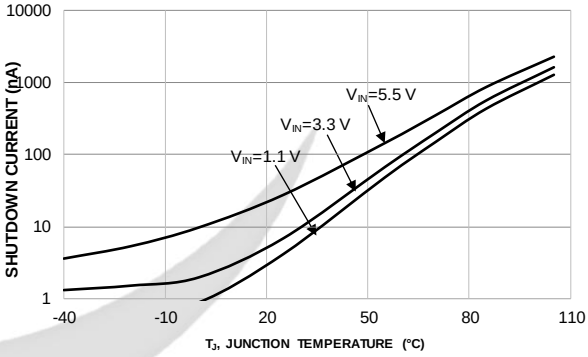

Figure 9. Shut Down Current vs. Temperature

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TYPICAL PERFORMANCE CHARACTERISTICS(CONTINUED)

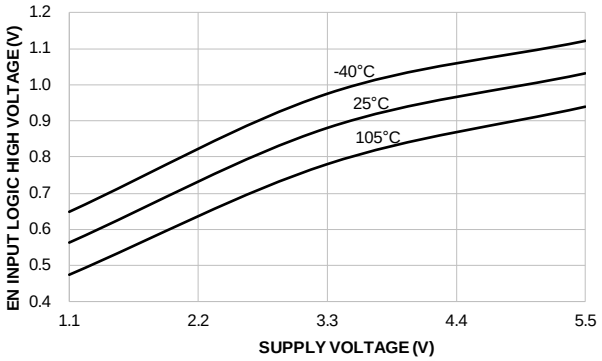

Figure 10. EN Input Logic High Voltage vs. Input Voltage

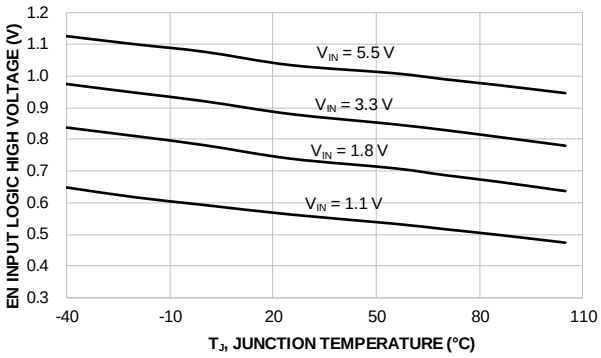

Figure 11. EN Input Logic High Voltage vs. Temperature

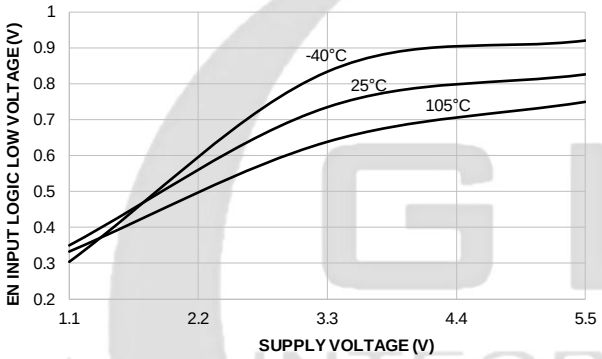

Figure 12. EN Input Logic Low Voltage vs. Input Voltage

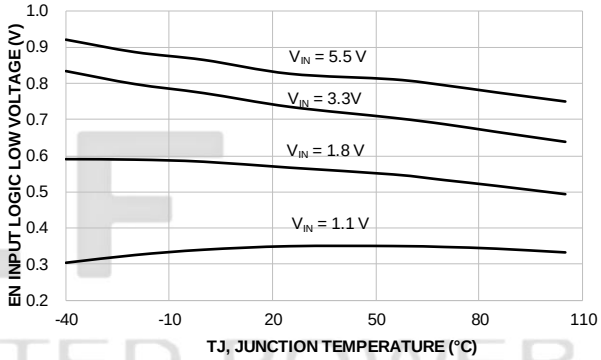

Figure 13. EN Input Logic Low Voltage vs. Temperature

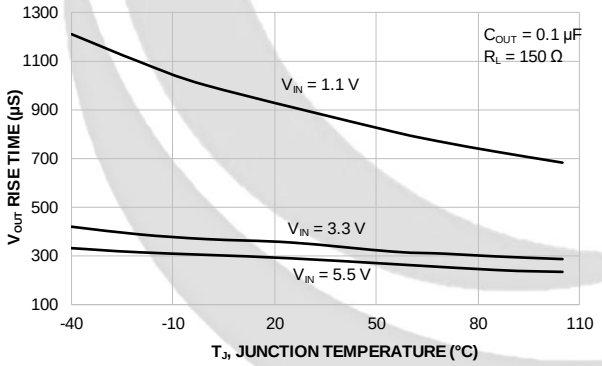

Figure 14. VOUT Rise Time vs. Temperature

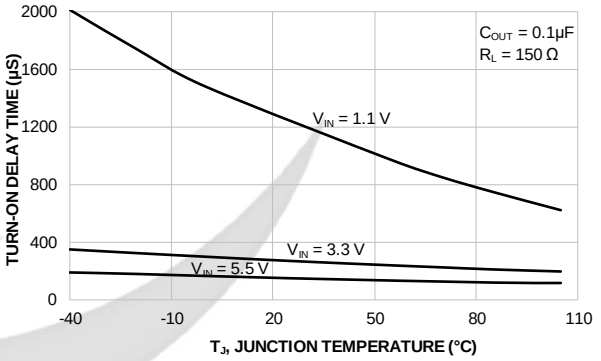

Figure 15. Turn-On Delay Time vs. Temperature

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TYPICAL PERFORMANCE CHARACTERISTICS(CONTINUED)

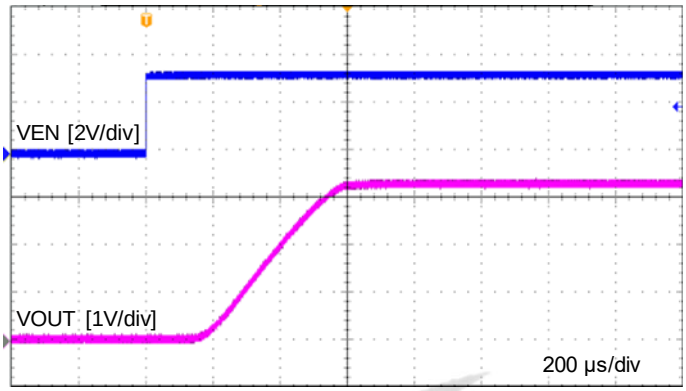

Figure 16. Turn-On Response

V_{IN}=3.3 V, C_{IN}=1.0 µF, C_{OUT}=0.1 µF, R_L=150 Ω

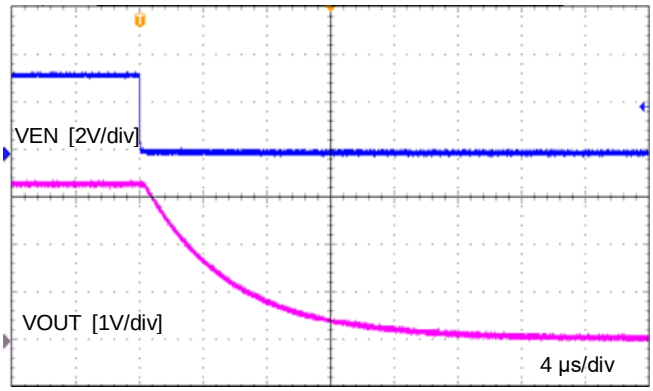

Figure 17. Turn-Off Response

V_{IN}=3.3 V, C_{IN}=1.0 µF, C_{OUT}=0.1 µF, R_L=150 Ω

APPLICATION INFORMATION

The GLF71311H is integrated 3 A, ultra-efficient I_QSmart™ load switch devices with a fixed slew rate control to limit the inrush current during turn on. Each device is capable of operating over a wide input range from 1.1 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current to avoid unwanted standby current and save limited input power. The package is a 0.97 mm x 0.97 mm x 0.55 mm wafer level chip scale package, saving space in compact applications. It is constructed using 4 bumps, with a 0.5 mm pitch for manufacturability.

Input Capacitor

The GLF71311H does not require an input capacitor. However, to reduce the voltage drop on the input power rail caused by transient inrush current at start-up, a 0.1 µF capacitor is recommended to be placed close to the V_{IN} pin. A higher input capacitor value can be used to further attenuate the input voltage drop.

Output Capacitor

The GLF71311H does not require an output capacitor. However, use of an output capacitor is recommended to mitigate voltage undershoot on the output pin when the switch is turning off. Undershoot can be caused by parasitic inductance from board traces or intentional load inductances. If load inductances do exist, use of an output capacitor can improve output voltage stability and system reliability. The C_{OUT} capacitor should be spaced close to the VOUT and GND pins.

EN pin

The GLF71311H can be activated by forcing EN pin high level. Note that the EN pin has an internal pull-down resistor to help pull the main switch to a known “off state” when no EN signal is applied from an external controller.

Output Discharge Function

The GLF71311H has an internal discharge N-channel FET switch on the VOUT pin. When EN signal turns the main power FET to an off state, the N-channel switch turns on to discharge an output capacitor quickly.

Board Layout

All traces should be as short as possible to minimize parasitic inductance effects. Wide traces for VIN, VOUT and GND will help reduce signal degradation and parasitic effects during dynamic operation as well as improve the thermal performance at high load current.

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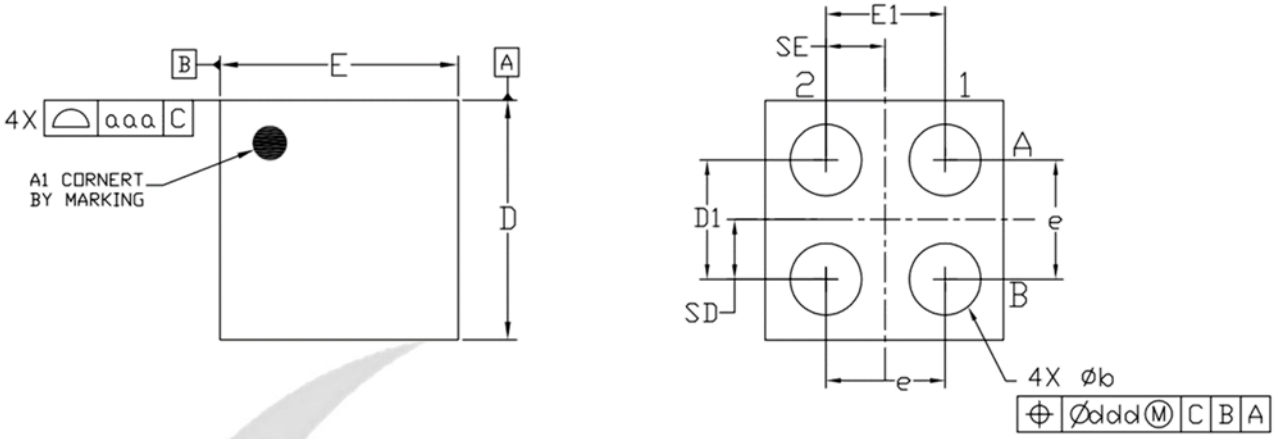
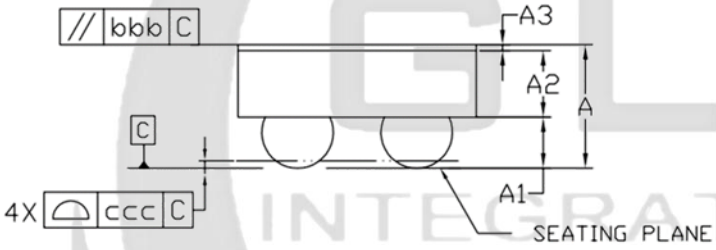
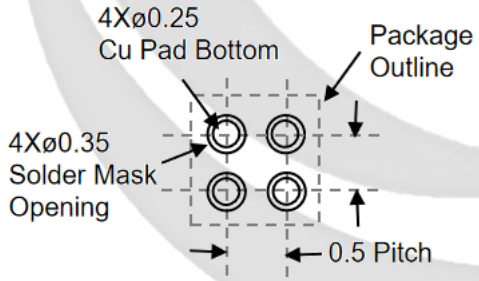
PACKAGE OUTLINE





Dimensional Ref.			
REF.	Min.	Nom.	Max.
A	0.500	0.550	0.600
A1	0.225	0.250	0.275
A2	0.255	0.275	0.300
A3	0.020	0.025	0.030
D	0.960	0.970	0.985
E	0.960	0.970	0.985
D1	0.450	0.500	0.550
E1	0.450	0.500	0.550
b	0.260	0.310	0.360
e	0.500 BSC		
SD	0.250 BSC		
SE	0.250 BSC		
Tol. of Form&Position			
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		

Recommended Footprint



Notes

1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREE)
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
3. A3: BACKSIDE LAMINATION

PACKAGING INFORMATION

Part Number	Package	Pins	Pitch	Top Mark	Moisture Sensitivity Level	Environmental Information
GLF71311H	WLCSP	4	0.50mm	DZ	MSL1	ROHS+HF

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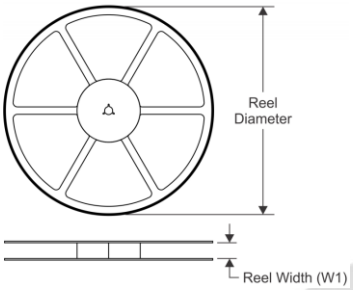
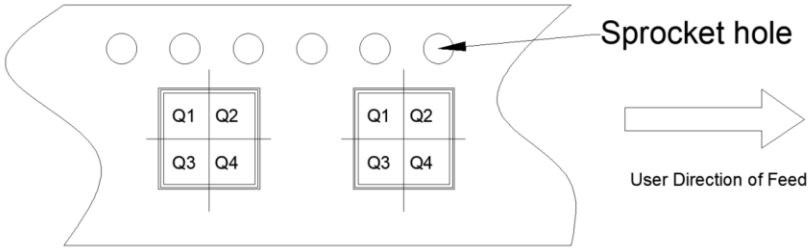
TAPE AND REEL INFORMATION

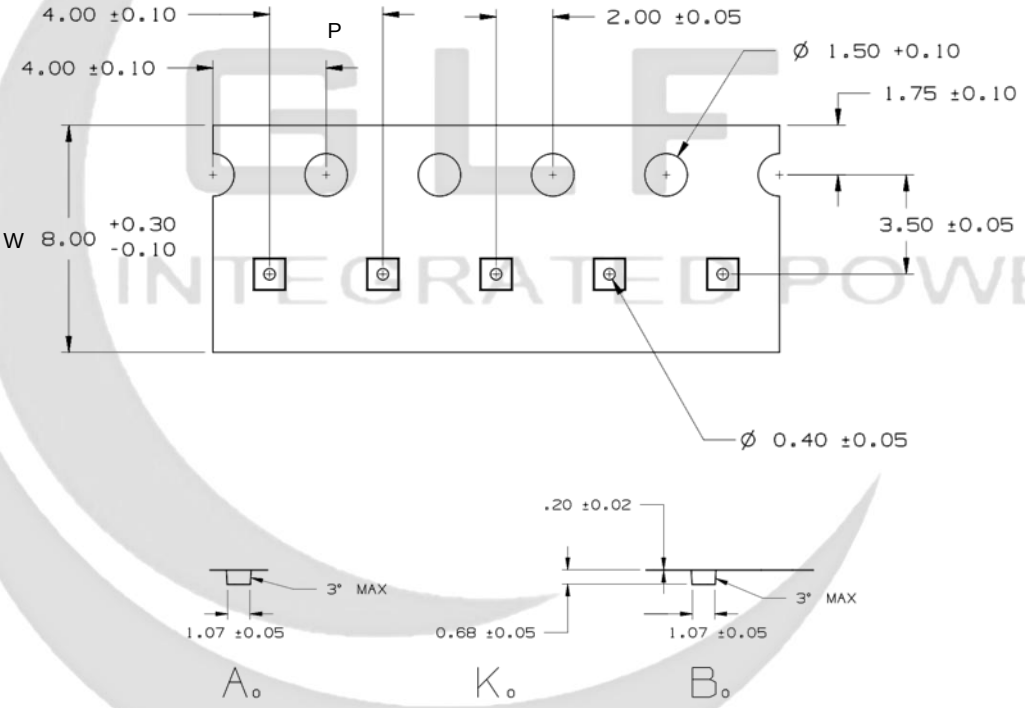
REEL DIMENSIONS



QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE



TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	A0	B0	K0	P	W	Pin1
GLF71311H	WLCSP	4	3000	180	9	1.07	1.07	0.68	4	8	Q1

Remark:

A0: Dimension designed to accommodate the component width

B0: Dimension designed to accommodate the component length

K0: Dimension designed to accommodate the component thickness

W: Overall width of the carrier tape

P: Pitch between successive cavity centers

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SPECIFICATION DEFINITIONS

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Parameters including the typical, minimum, and maximum values are desired, or target. GLF reserves the right to change contents at any time without warning or notification. A target specification will not guarantee the future production of the device.	Design / Development
Preliminary Specification	This is a draft version of a product specification which is under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification will not guarantee the future production of the device.	Qualification
Product Specification	This document represents the characteristics of the device.	Production

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